SKD 110



SEMIPONT® 4

Power Bridge Rectifiers

SKD 110

Features

- Robust plastic case with screw terminals
- · Large, isolated base plate
- Blocking voltage up to 1800 V
- · High surge currents
- Three phase bridge rectifier
- · Easy chassis mounting
- UL recognized, file no. E 63 532

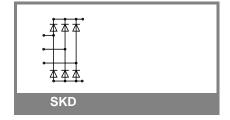
Typical Applications

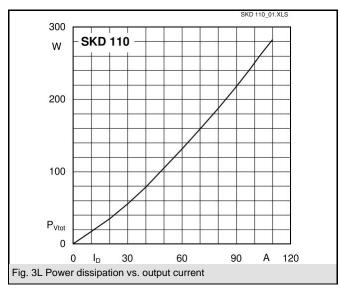
- Three phase rectifiers for power supplies
- Input rectifiers for variable frequency drives
- Rectifiers for DC motor field supplies
- · Battery charger rectifiers
- 1) Available in limited quantities
- Mounted on a painted metal sheet of min. 250 x 250 x 1 mm;

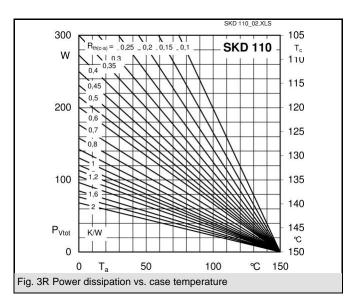
$$R_{th(c-a)} = 1.8 \text{ K/W}$$

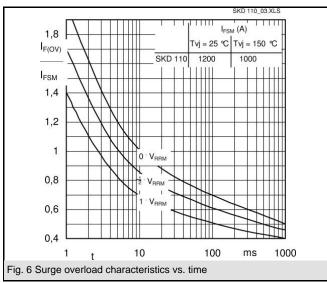
V_{RSM}	V_{RRM}, V_{DRM}	I _D = 110 A (full conduction)
V	V	(T _c = 100 °C)
400	400	SKD 110/04
800	800	SKD 110/08
1200	1200	SKD 110/12
1400	1400	SKD 110/14
1600	1600	SKD 110/16
1800	1800	SKD 110/18 ¹⁾

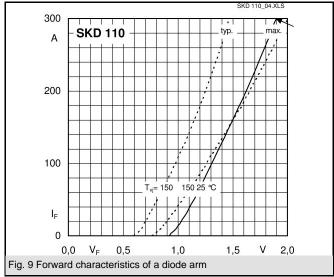
Symbol	Conditions	Values	Units
I _D	T _c = 85 °C	151	Α
_	$T_a = 45 ^{\circ}\text{C}$; chassis ²⁾	28	Α
	T _a = 45 °C; P1/200	70	Α
	T _a = 35 °C; P1/120 F	110	Α
	T _a = 35 °C; P3/120 F	123	Α
I _{FSM}	T _{vj} = 25 °C; 10 ms	1200	A
	T _{vi} = 150 °C; 10 ms	1000	Α
i²t	T _{vj} = 25 °C; 8,3 10 ms	7200	A²s
	T _{vj} = 150 °C; 8,3 10 ms	5000	A²s
V _F	T _{vi} = 25 °C; I _F = 300 A	max. 1,9	V
V _(TO)	T _{vi} = 150 °C	max. 0,85	V
r _T	T _{vi} = 150 °C	max. 4	mΩ
I_{RD}	$T_{vj} = 25 \text{ °C}; V_{DD} = V_{DRM}; V_{RD} = V_{RRM}$	max. 0,5	mA
	T_{vj}^{*} = 150 °C, $V_{RD} = V_{RRM}$	5	mA
R _{th(j-c)}	per diode	0,9	K/W
uig-c)	total	0,15	K/W
$R_{\text{th(c-s)}}$	total	0,03	K/W
T _{vi}		- 40 + 150	°C
T _{stg}		- 40 + 125	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 (3000)	V
M _s	to heatsink	5 ± 15 %	Nm
M _t	to terminals	5 ± 15 %	Nm
m		270	g
Case		G 37	

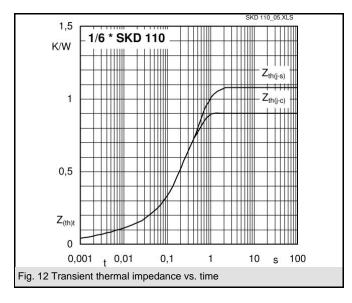


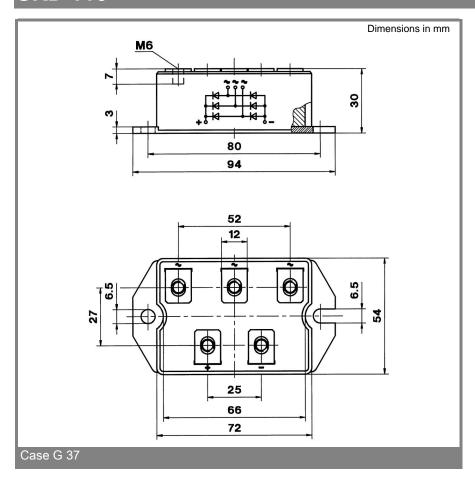












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